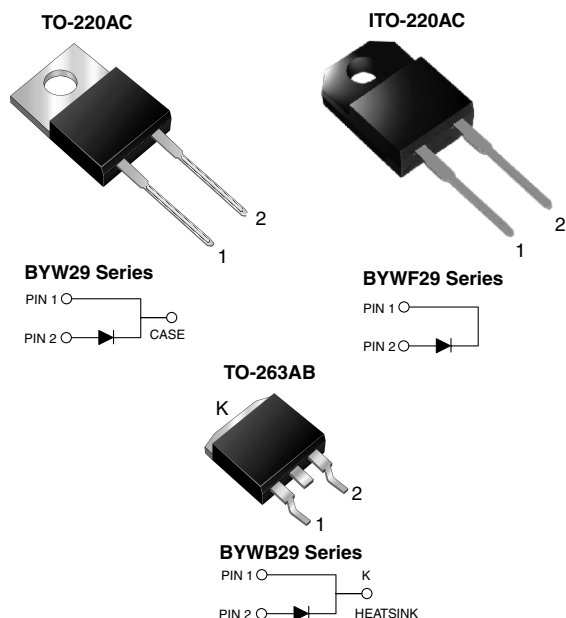


Ultrafast Rectifier



FEATURES

- Glass passivated chip junction
- Ultrafast recovery time
- Low switching losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- Meets MSL level 1, per J-STD-020C, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AC and ITO-220AC package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, dc-to-dc converters, and other power switching application.

MECHANICAL DATA

Case: TO-220AC, ITO-220AC, TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

E3 suffix for commercial grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	8.0 A
V_{RRM}	50 V to 200 V
I_{FSM}	100 A
t_{rr}	25 ns
V_F	0.8 V
$T_J \text{ max.}$	150 °C

MAXIMUM RATINGS ($T_C = 25 \text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	BYW29-50	BYW29-100	BYW29-150	BYW29-200	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	V
Maximum RMS voltage	V_{RMS}	35	70	105	140	V
Maximum DC blocking voltage	V_{DC}	50	100	150	200	V
Maximum average forward rectified current at $T_C = 105 \text{ °C}$	$I_{F(AV)}$	8.0				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	100				A
Operating and storage temperature range	T_J, T_{STG}	- 65 to + 150				°C
Isolation voltage (ITO-220AC only) from terminal to heatsink $t = 1 \text{ min}$	V_{AC}	1500				V

BYW(F,B)29-50 thru BYW(F,B)29-200

Vishay General Semiconductor



ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	BYW29-50	BYW29-100	BYW29-150	BYW29-200	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	I _F = 20 A I _F = 8.0 A	T _J = 25 °C T _J = 150 °C	V _F	1.3 0.8				V
Maximum DC reverse current at rated DC blocking voltage		T _C = 25 °C T _C = 100 °C	I _R	10 500				μA
Maximum reverse recovery time	I _F = 1 A, V _R = 30 V, dI/dt = 100 A/μs, I _{rr} = 10 % I _{RM}		t _{rr}	25				ns
Typical junction capacitance	4.0 V, 1 MHz		C _J	45				pF

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	BYW	BYWF	BYWB	UNIT
Typical thermal resistance from junction to case per leg	$R_{\theta JC}$	2.5	5.5	2.5	$^{\circ}\text{C}/\text{W}$

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AC	BYW29-200-E3/45	1.80	45	50/tube	Tube
ITO-220AC	BYWF29-200-E3/45	1.95	45	50/tube	Tube
TO-263AB	BYWB29-200-E3/45	1.77	45	50/tube	Tube
TO-263AB	BYWB29-200-E3/81	1.77	81	800/reel	Tape reel
TO-220AC	BYW29-200HE3/45 ⁽¹⁾	1.80	45	50/tube	Tube
ITO-220AC	BYWF29-200HE3/45 ⁽¹⁾	1.95	45	50/tube	Tube
TO-263AB	BYWB29-200HE3/45 ⁽¹⁾	1.77	45	50/tube	Tube
TO-263AB	BYWB29-200HE3/81 ⁽¹⁾	1.77	81	800/reel	Tape reel

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

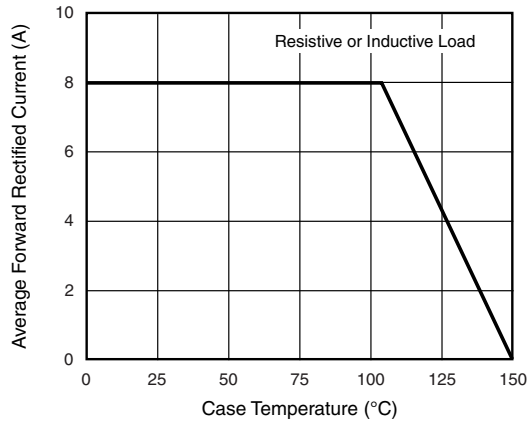


Figure 1. Maximum Forward Current Derating Curve

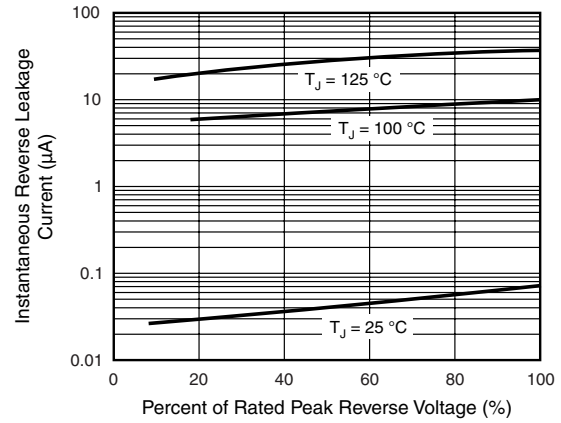


Figure 4. Typical Reverse Leakage Characteristics

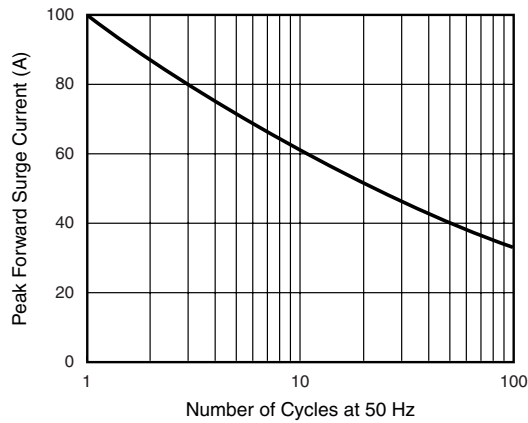


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

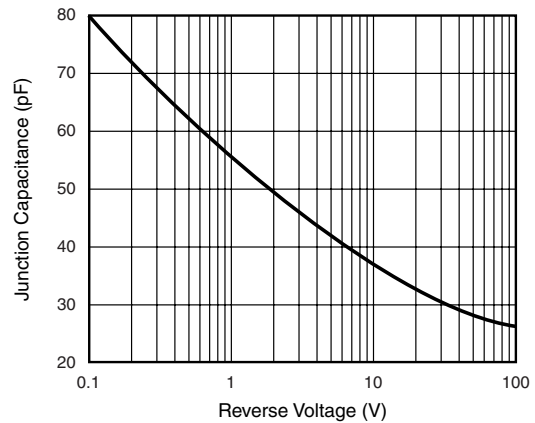


Figure 5. Typical Junction Capacitance

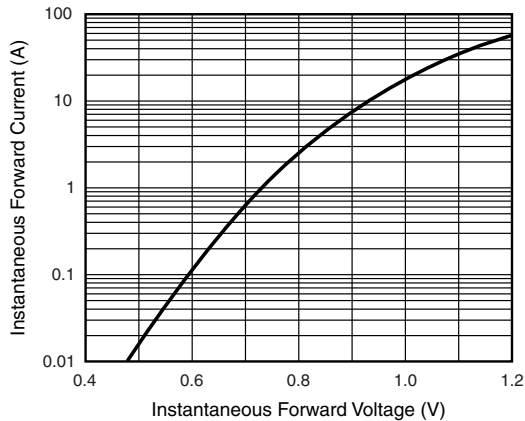


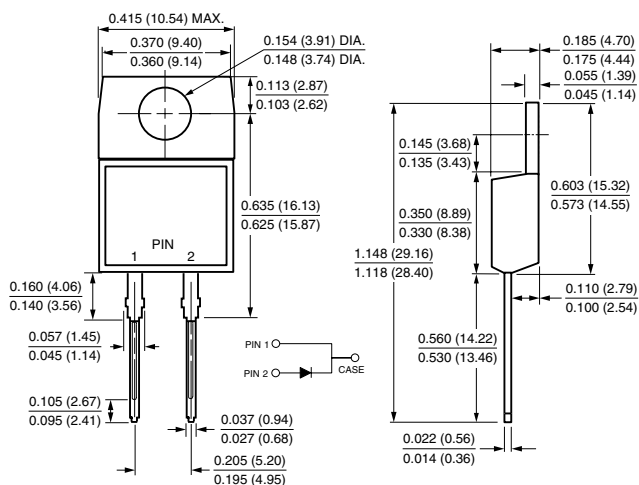
Figure 3. Typical Instantaneous Forward Characteristics

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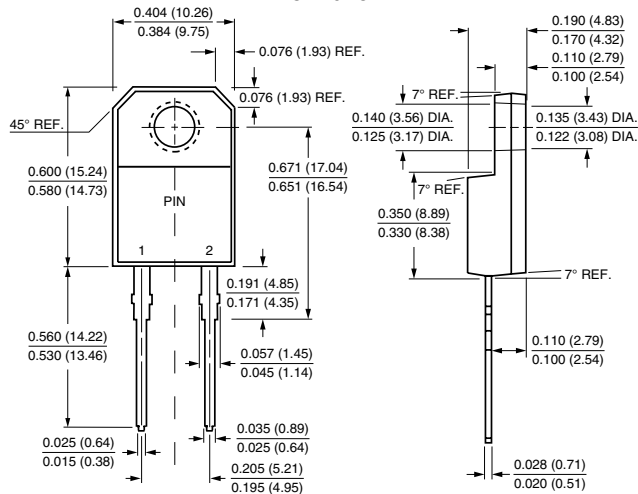


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

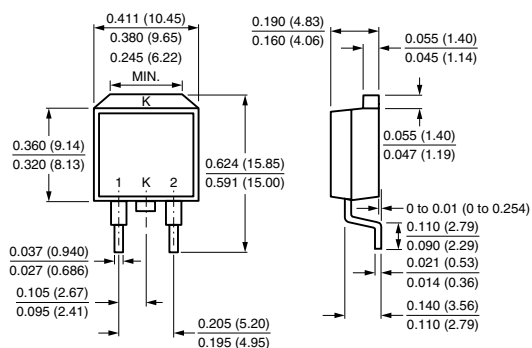
TO-220AC



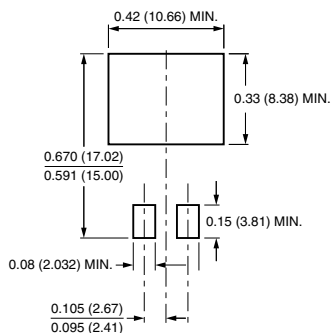
ITO-220AC



TO-263AB



Mounting Pad Layout





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